

## Features

- Single Voltage Operation Read/Write: 2.65V - 3.6V
- Access Time – 70 ns
- Sector Erase Architecture
  - One Hundred Twenty-seven 32K Word (64K Bytes) Main Sectors with Individual Write Lockout
  - Eight 4K Word (8K Bytes) Sectors with Individual Write Lockout
- Fast Word Program Time – 10 µs
- Typical Sector Erase Time: 32K Word Sectors – 700 ms; 4K Word Sectors – 100 ms
- Suspend/Resume Feature for Erase and Program
  - Supports Reading and Programming Data from Any Sector by Suspending Erase of a Different Sector
  - Supports Reading Any Word by Suspending Programming of Any Other Word
- Low-power Operation
  - 10 mA Active
  - 15 µA Standby
- VPP Pin for Write Protection and Accelerated Program Operation
- RESET Input for Device Initialization
- Softlock Sector Protection
- Secure Lock and Freeze Feature
- Top or Bottom Boot Block Configuration Available
- 128-bit Protection Register
- Minimum 100,000 Erase Cycles
- Common Flash Interface (CFI)
- CBGA Green (Pb/Halide-free/RoHS Compliant) Packaging

## 1. Description

The AT49BV640S(T) is a 2.7-volt 32-megabit Flash memory organized as 4,194,304 words of 16 bits each. The memory is divided into 135 sectors for erase operations. The device is offered in a 64-ball CBGA package. The device has  $\overline{CE}$  and  $\overline{OE}$  control signals to avoid any bus contention. This device can be read or reprogrammed using a single power supply, making it ideally suited for in-system programming.

The device powers on in the read mode. Command sequences are used to place the device in other operation modes such as program and erase. The device has the capability to protect the data in any sector (see “[Softlock Sector Protection](#)” on [page 6](#)).

To increase the flexibility of the device, it contains an Erase Suspend and Program Suspend feature. This feature will put the erase or program on hold for any amount of time and let the user read data from or program data to any of the remaining sectors within the memory.

The VPP pin provides data protection. When the  $V_{PP}$  input is below 0.4V, the program and erase functions are inhibited. When  $V_{PP}$  is at 1.65V or above, normal program and erase operations can be performed. With  $V_{PP}$  at 10.0V, the program (Dual-word Program command) operation is accelerated.



**64-megabit  
(4M x 16)  
Secure  
3-volt Only  
Memory**

**AT49BV640S  
AT49BV640ST**

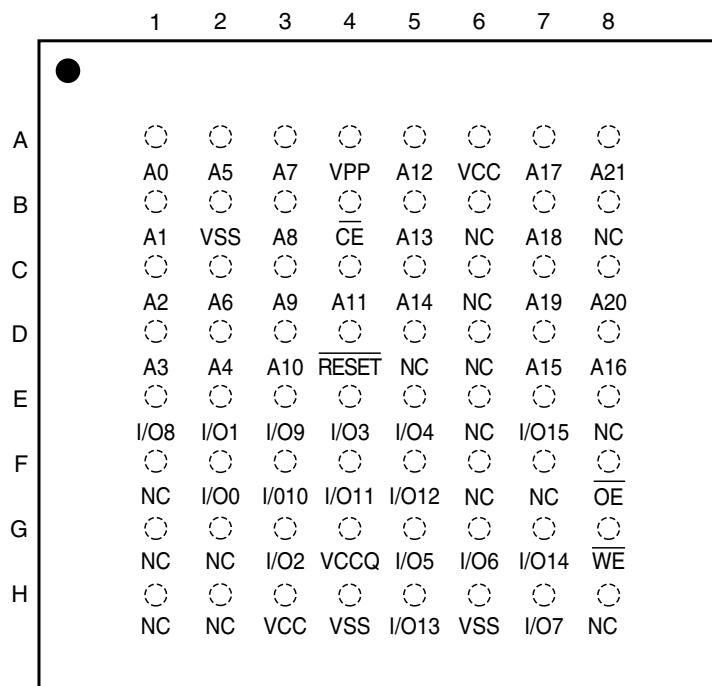


**ATMEL CONFIDENTIAL:  
Under Non-Disclosure Agreement (NDA)**

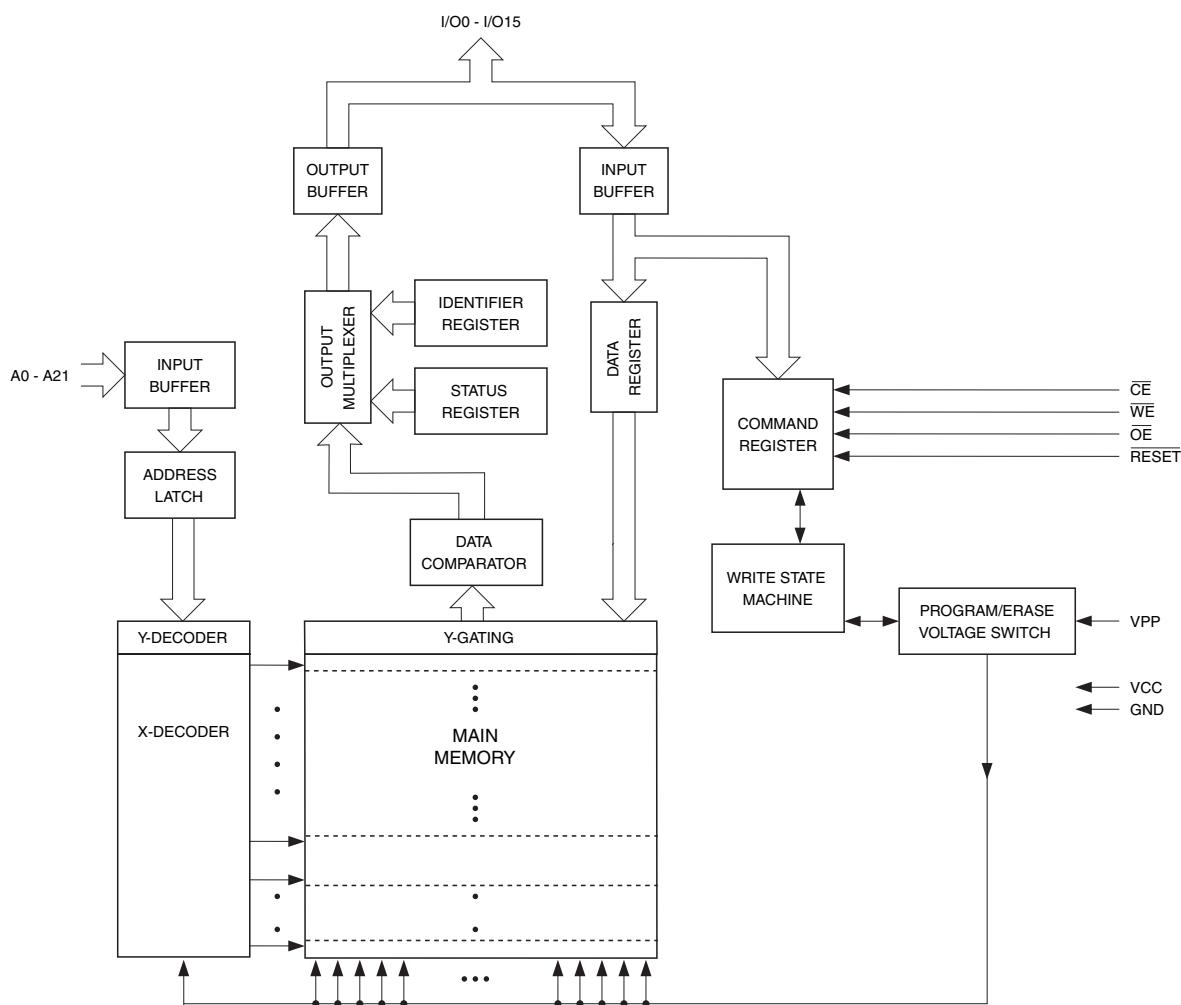
## 2. Pin Configurations

| Pin Name           | Pin Function   |
|--------------------|--|
| A0 - A21           | Addresses  |
| $\overline{CE}$    | Chip Enable  |
| $\overline{OE}$    | Output Enable  |
| $\overline{WE}$    | Write Enable   |
| $\overline{RESET}$ | Reset  |
| VPP                | Write Protection and Power Supply for Accelerated Program Operations |
| I/O0 - I/O15       | Data Inputs/Outputs  |
| NC                 | No Connect   |
| VCCQ               | Output Power Supply  |

### 2.1 64-ball CBGA Top View



### 3. Block Diagram



### 4. Device Operation

#### 4.1 Command Sequences

When the device is first powered on, it will be in the read mode. Command sequences are used to place the device in other operating modes such as program and erase. The command sequences are written by applying a low pulse on the **WE** input with **CE** low and **OE** high or by applying a low-going pulse on the **CE** input with **WE** low and **OE** high. The address is latched on the first rising edge of the **WE** or **CE**. Valid data is latched on the rising edge of the **WE** or **CE** pulse, whichever occurs first. The addresses used in the command sequences are not affected by entering the command sequences.

#### 4.2 Read

The AT49BV640S(T) is accessed like an EPROM. When **CE** and **OE** are low and **WE** is high, the data stored at the memory location determined by the address pins are asserted on the outputs. The outputs are put in the high impedance state whenever **CE** or **OE** is high. This dual-line control gives designers flexibility in preventing bus contention.

## 4.3 Reset

A  $\overline{\text{RESET}}$  input pin is provided to ease some system applications. When  $\overline{\text{RESET}}$  is at a logic high level, the device is in its standard operating mode. A low level on the  $\overline{\text{RESET}}$  pin halts the present device operation and puts the outputs of the device in a high-impedance state. When a high level is reasserted on the  $\overline{\text{RESET}}$  pin, the device returns to read mode.

## 4.4 Erase

Before a word can be reprogrammed it must be erased. The erased state of the memory bits is a logical “1”. The individual sectors can be erased by using the Sector Erase command.

### 4.4.1 Sector Erase

The device is organized into 135 sectors (SA0 - SA134) that can be individually erased. The Sector Erase command is a two-bus cycle operation. The sector address and the D0H Data Input command are latched on the rising edge of  $\overline{\text{WE}}$ . The sector erase starts after the rising edge of  $\overline{\text{WE}}$  of the second cycle provided the given sector has not been protected. The erase operation is internally controlled; it will automatically time to completion. The maximum time to erase a sector is  $t_{\text{SEC}}$ . An attempt to erase a sector that has been protected will result in the operation terminating immediately.

## 4.5 Word Programming

Once a memory sector is erased, it is programmed (to a logical “0”) on a word-by-word basis. Programming is accomplished via the Internal Device Command register and is a two-bus cycle operation. The device will automatically generate the required internal program pulses.

Any commands except Read Status Register, Program Suspend and Program Resume written to the chip during the embedded programming cycle will be ignored. If a hardware reset happens during programming, the data at the location being programmed will be corrupted. Please note that a data “0” cannot be programmed back to a “1”; only erase operations can convert “0”s to “1”s. Programming is completed after the specified  $t_{\text{BP}}$  cycle time. If the program status bit is a “1”, the device was not able to verify that the program operation was performed successfully. The status register indicates the programming status. While the program sequence executes, status bit I/O7 is “0”.

## 4.6 VPP Pin

The circuitry of the AT49BV640S(T) is designed so that the device cannot be programmed or erased if the  $V_{\text{PP}}$  voltage is less than 0.4V. When  $V_{\text{PP}}$  is at 1.65V or above, normal program and erase operations can be performed. The VPP pin cannot be left floating.

## 4.7 Read Status Register

The status register indicates the status of device operations and the success/failure of that operation. The Read Status Register command causes subsequent reads to output data from the status register until another command is issued. To return to reading from the memory, issue a Read command.

The status register bits are output on I/O7 - I/O0. The upper byte, I/O15 - I/O8, outputs 00H when a Read Status Register command is issued.

The contents of the status register [SR7:SR0] are latched on the falling edge of  $\overline{OE}$  or  $\overline{CE}$  (whichever occurs last), which prevents possible bus errors that might occur if status register contents change while being read.  $\overline{CE}$  or  $\overline{OE}$  must be toggled with each subsequent status read, or the status register will not indicate completion of a Program or Erase operation.

When the Write State Machine (WSM) is active, SR7 will indicate the status of the WSM; the remaining bits in the status register indicate whether the WSM was successful in performing the preferred operation (see [Table 4-1](#)).

**Table 4-1.** Status Register Bit Definition

| WSMS  | ESS | ES | PRS | VPPS  | PSS | SLS | R |
|---|-----|----|-----|---|-----|-----|---|
| 7   | 6   | 5  | 4   | 3   | 2   | 1   | 0 |
|   |     |    |     | <b>Notes</b>  |     |     |   |
| SR7 WRITE STATE MACHINE STATUS (WSMS)<br>1 = Ready<br>0 = Busy  |     |    |     | Check Write State Machine bit first to determine Word Program or Sector Erase completion, before checking program or erase status bits.   |     |     |   |
| SR6 = ERASE SUSPEND STATUS (ESS)<br>1 = Erase Suspended<br>0 = Erase In Progress/Completed  |     |    |     | When Erase Suspend is issued, WSM halts execution and sets both WSMS and ESS bits to "1" – ESS bit remains set to "1" until an Erase Resume command is issued.  |     |     |   |
| SR5 = ERASE STATUS (ES)<br>1 = Error in Sector Erase<br>0 = Successful Sector Erase   |     |    |     | When this bit is set to "1", WSM has applied the max number of erase pulses to the sector and is still unable to verify successful sector erasure.  |     |     |   |
| SR4 = PROGRAM STATUS (PRS)<br>1 = Error in Programming<br>0 = Successful Programming  |     |    |     | When this bit is set to "1", WSM has attempted but failed to program a word   |     |     |   |
| SR3 = VPP STATUS (VPPS)<br>1 = VPP Low Detect, Operation Abort<br>0 = VPP OK  |     |    |     | The $V_{PP}$ status bit does not provide continuous indication of VPP level. The WSM interrogates $V_{PP}$ level only after the Program or Erase command sequences have been entered and informs the system if $V_{PP}$ has not been switched on. The $V_{PP}$ is also checked before the operation is verified by the WSM. |     |     |   |
| SR2 = PROGRAM SUSPEND STATUS (PSS)<br>1 = Program Suspended<br>0 = Program in Progress/Completed  |     |    |     | When Program Suspend is issued, WSM halts execution and sets both WSMS and PSS bits to "1". PSS bit remains set to "1" until a Program Resume command is issued.  |     |     |   |
| SR1 = SECTOR LOCK STATUS (SLS)<br>1 = Prog/Erase attempted on a locked sector; Operation aborted.<br>0 = No operation to locked sectors |     |    |     | If a Program or Erase operation is attempted to one of the locked sectors, this bit is set by the WSM. The operation specified is aborted and the device is returned to read status mode.   |     |     |   |
| SR0 = Reserved for Future Enhancements (R)  |     |    |     | This bit is reserved for future use and should be masked out when polling the status register.  |     |     |   |

Note: 1. A Command Sequence Error is indicated when SR1, SR3, SR4 and SR5 are set.



## 4.8 Clear Status Register

The WSM can set status register bits 1 through 7 and can clear bits 2, 6 and 7; but, the WSM cannot clear status register bits 1, 3, 4 or 5. Because bits 1, 3, 4 and 5 indicate various error conditions, these bits can be cleared only through the Clear Status Register command. By allowing the system software to control the resetting of these bits, several operations may be performed (such as cumulatively programming several addresses or erasing multiple sectors in sequence) before reading the status register to determine if an error occurred during those operations. The status register should be cleared before beginning another operation. The Read command must be issued before data can be read from the memory array. The status register can also be cleared by resetting the device.

## 4.9 Softlock Sector Protection

The AT49BV640S(T) offers the Softlock Sector Protection mode. Once this mode is enabled, the contents of the selected sector is read-only and cannot be erased or programmed. At power-up and reset, all sectors have their Softlock protection mode enabled.

### 4.9.1 Unlock

The Softlock protection mode can be disabled by issuing a two-bus cycle Unlock command to the selected sector. Once a sector is unlocked, its contents can be erased or programmed. To enable the Softlock protection mode, a two-bus cycle Softlock command must be issued to the selected sector.

### 4.9.2 Sector Protection Detection

A software method is available to determine if the Softlock Sector Protection feature is enabled. When the device is in the software product identification mode a read from I/O0 at address location 00002H within a sector will show if the sector is unlocked or softlocked.

**Table 4-2.** Softlock Sector Protection Status

| I/O0 | Sector Protection Status |
|------|--------------------------|
| 0    | Sector Not Locked        |
| 1    | Softlock Enabled         |

## 4.10 Secure Lock

In some applications, in addition to the standard softlock sector protection mechanism, a requirement exists to allow for the permanent and irreversible locking of selected regions in the memory. The AT49BV640S(T) allows the user to permanently lock thirty-eight regions, and once activated these secure regions cannot be altered or erased through Software or Hardware at any time. Once activated, no facility exists to over-ride the secure lock mechanism. The size and the location of the secure regions is determined by the Top or Bottom Boot Block designation. The location of the secure regions is shown on [pages 17 - 20](#).

The secure regions can be locked in any sequence and at any time during normal device operation. Read operations can still be performed on any region that has the secure lock feature enabled. Full read/write operations and standard sector operations including standard Sector locking can be performed on all regions that are not secure locked.

To secure lock a region, a two-bus cycle command must be used as shown in the “[Command Definition Table](#)”. The data programmed during the second bus cycle in bits D15 - D0 determines whether a corresponding region is secure locked or not. If data bit DX is “0”, the corresponding region, SCR<sub>X</sub>, shown below will be secure locked. If data bit DX is “1”, the corresponding region shown below will not be secure locked.

**Table 4-3.** Secure Lock Table

|   | D15   | D14   | D13   | D12   | D11   | D10        | D9    | D8    | D7    | D6    | D5    | D4    | D3    | D2    | D1   | D0   |
|---|-------|-------|-------|-------|-------|------------|-------|-------|-------|-------|-------|-------|-------|-------|--|------|
| D <sub>IN1</sub> , data programmed during 2nd bus cycle of Lock SCR7 - SCR0 Command   | X     | X     | X     | X     | X     | Freeze Bit | SCR7  | SCR6  | SCR5  | SCR4  | SCR3  | SCR2  | SCR1  | SCR0  | Protection Register – Block B <sup>(1)</sup> | X    |
| D <sub>IN2</sub> , data programmed during 2nd bus cycle of Lock SCR23 - SCR8 Command  | SCR23 | SCR22 | SCR21 | SCR20 | SCR19 | SCR18      | SCR17 | SCR16 | SCR15 | SCR14 | SCR13 | SCR12 | SCR11 | SCR10 | SCR9   | SCR8 |
| D <sub>IN3</sub> , data programmed during 3rd bus cycle of Lock SCR37 - SCR24 Command | X     | SCR37 | SCR36 | SCR35 | SCR34 | SCR33      | SCR32 | SCR31 | SCR30 | SCR29 | SCR28 | SCR27 | SCR26 | SCR25 | SCR24  | X    |

Note: 1. Protection Register – Block B refers to the user-programmable region of the 128-bit protection register. For details, see section [“128-bit Protection Register” on page 8](#).

To determine whether a secure region is locked or not, the status of SCR command is given, and data bits D15 - D0 are read. If the data bit is “0”, the corresponding region is secure locked, if the data bit is “1”, the corresponding region can be programmed.

#### **4.11 Erase Suspend/Erase Resume**

The Erase Suspend command allows the system to interrupt a sector erase operation and then program or read data from a different sector within the memory. After the Erase Suspend command is given, the device requires a maximum time of 15 µs to suspend the erase operation. After the erase operation has been suspended, the system can then read data or program data to any other sector within the device. An address is not required during the Erase Suspend command. During a sector erase suspend, another sector cannot be erased. To resume the sector erase operation, the system must write the Erase Resume command. The Erase Resume command is a one-bus cycle command. The only valid commands while erase is suspended are Read Status Register, Product ID Entry, CFI Query, Program, Program Resume, Erase Resume, Sector Softlock and Sector Unlock.

#### **4.12 Program Suspend/Program Resume**

The Program Suspend command allows the system to interrupt a programming operation and then read data from a different word within the memory. After the Program Suspend command is given, the device requires a maximum of 10 µs to suspend the programming operation. After the programming operation has been suspended, the system can then read from any other word within the device. An address is not required during the program suspend operation. To resume the programming operation, the system must write the Program Resume command. The program suspend and resume are one-bus cycle commands. The command sequence for the erase suspend and program suspend are the same, and the command sequence for the erase resume and program resume are the same. Read, Read Status Register, Product ID Entry, Program Resume are valid commands during a Program Suspend.

#### **4.13 Product Identification**

The product identification mode identifies the device and manufacturer as Atmel. It may be accessed by a software operation. For details, see “[Operating Modes](#)” on page 21.

#### **4.14 128-bit Protection Register**

The AT49BV640S(T) contains a 128-bit register that can be used for security purposes in system design. The protection register is divided into two 64-bit blocks. The two blocks are designated as block A and block B. The data in block A is non-changeable and is programmed at the factory with a unique number. The data in block B is programmed by the user and can be locked out such that data in the sector cannot be reprogrammed. To program block B in the protection register, the two-bus cycle Program Protection Register command must be used as shown in the “[Command Definition Table](#)” on page 15. To lock out block B, the two-bus cycle Lock Protection Register command must be used as shown in the “[Command Definition Table](#)”. Data bit D1 must be zero during the second bus cycle. To determine whether block B is locked out, use the status of block B protection command. If data bit D1 is zero, block B is locked. If data bit D1 is one, block B can be reprogrammed. Please see the “[Protection Register Addressing Table](#)” on page 16 for the address locations in the protection register. To read the protection register, the Product ID Entry command is given followed by a normal read operation from an address within the protection register. After determining whether block B is protected or not, or reading the protection register, the Read command must be given to return to the read mode.

#### **4.15 Freeze Feature**

The AT49BV640S(T) device contains a freeze feature that will freeze the lock status of the secure regions and the lock status of protection register B. The freeze feature prevents any further locking of the secure regions and also prevents any change to the lock status of protection register B. If the user requires certain regions to be locked, then these regions must be programmed and locked prior to activation of the freeze command. It is important to note that enabling the freeze feature is irreversible.

To enable the freeze feature, during the second bus cycle of the Lock Protection Register (Block B), Lock SCR7-SCR0 command, bit D10 must be a “0”, and bits D9 - D1 must be all “1s”. This bit sequence is used to prevent inadvertent activation of the freeze feature. Although enabling the freeze feature requires D9 - D1 to be all “1s”, the lock status of the secure regions and protection register B will not change to the unlocked state by enabling the freeze feature.

#### **4.16 Common Flash Interface (CFI)**

CFI is a published, standardized data structure that may be read from a flash device. CFI allows system software to query the installed device to determine the configurations, various electrical and timing parameters, and functions supported by the device. CFI is used to allow the system to learn how to interface to the flash device most optimally. The two primary benefits of using CFI are ease of upgrading and second source availability. The command to enter the CFI Query mode is a one-bus cycle command which requires writing data 98h to any address. The CFI Query command can be written when the device is ready to read data or can also be written when the part is in the product ID mode. Once in the CFI Query mode, the system can read CFI data at the addresses given in [“Common Flash Interface Definition Table” on page 26](#). To return to the read mode, the read command should be issued.

#### **4.17 Hardware Data Protection**

Hardware features protect against inadvertent programs to the AT49BV640S(T) in the following ways: (a)  $V_{CC}$  sense: if  $V_{CC}$  is below 1.8V (typical), the device is reset and the program and erase functions are inhibited. (b) Program inhibit: holding any one of  $\overline{OE}$  low,  $\overline{CE}$  high or  $\overline{WE}$  high inhibits program cycles. (c) Program inhibit:  $V_{PP}$  is less than  $V_{ILPP}$ .

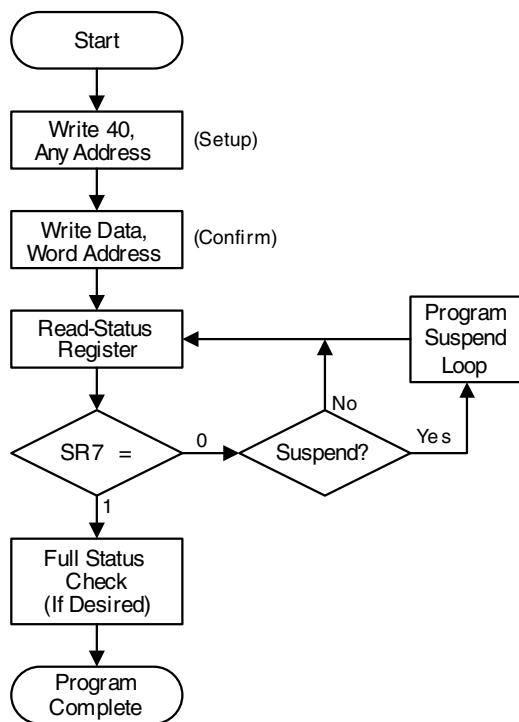
#### **4.18 Input Levels**

While operating with a 2.65V to 3.6V power supply, the address inputs and control inputs ( $\overline{OE}$ ,  $\overline{CE}$  and  $\overline{WE}$ ) may be driven from 0 to 5.5V without adversely affecting the operation of the device. The I/O lines can be driven from 0 to  $V_{CCQ} + 0.6V$ .

#### **4.19 Output Levels**

For the AT49BV640S(T), output high levels are equal to  $V_{CCQ} - 0.1V$  (not  $V_{CC}$ ). For 2.65V to 3.6V output levels,  $V_{CCQ}$  must be tied to  $V_{CC}$ .

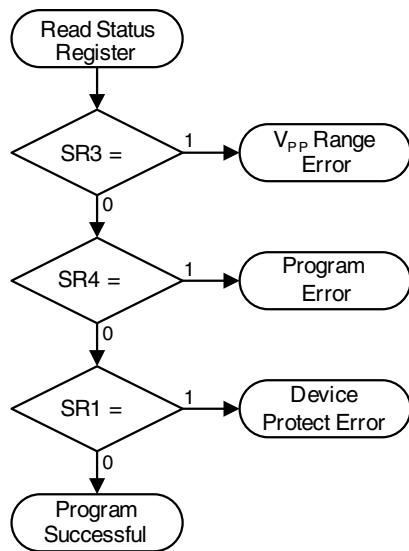
#### 4.20 Word Program Flowchart



#### 4.21 Word Program Procedure

| Bus Operation  | Command       | Comments  |
|--|---------------|---|
| Write  | Program Setup | Data = 40<br>Addr = Any Address                                 |
| Write  | Data          | Data = Data to program<br>Addr = Location to program            |
| Read   | None          | Status register data: Toggle CE or OE to update status register |
| Idle   | None          | Check SR7<br>1 = WSM Ready<br>0 = WSM Busy                      |
| Repeat for subsequent Word Program operations.<br>Full status register check can be done after each program, or after a sequence of program operations.<br>Write FF after the last operation to set to the Read state. |               |   |

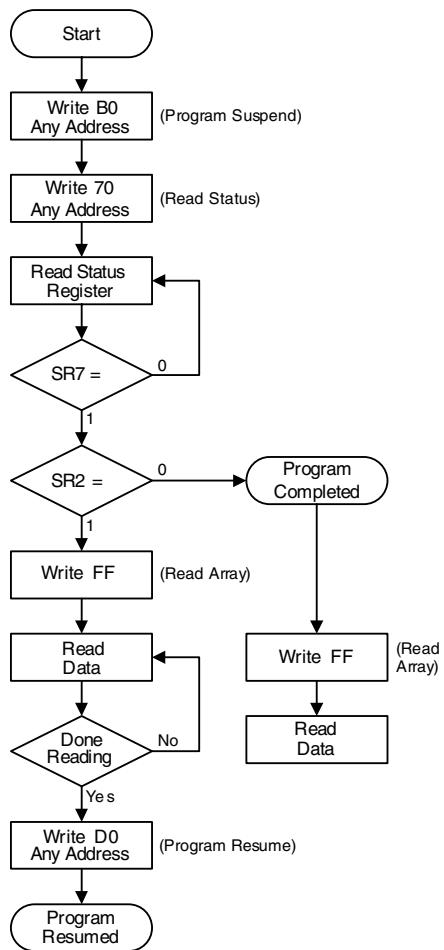
#### 4.22 Full Status Check Flowchart



#### 4.23 Full Status Check Procedure

| Bus Operation  | Command | Comments   |
|--|---------|--|
| Idle   | None    | Check SR3:<br>1 = V <sub>PP</sub> Error            |
| Idle   | None    | Check SR4:<br>1 = Data Program Error               |
| Idle   | None    | Check SR1:<br>1 = Sector locked; operation aborted |
| SR3 MUST be cleared before the Write State Machine allows further program attempts.<br>If an error is detected, clear the status register before continuing operations – only the Clear Status Register command clears the status register error bits. |         |  |

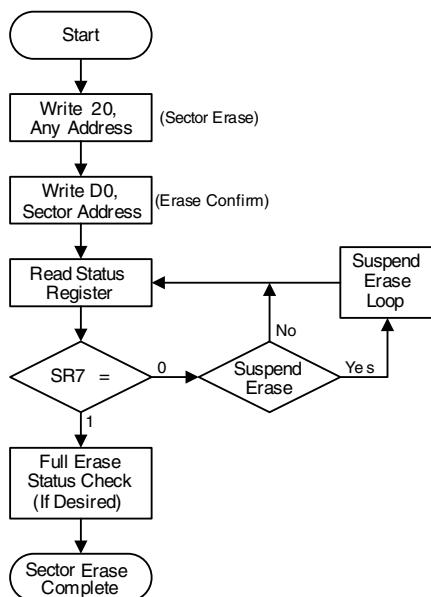
## 4.24 Program Suspend/Resume Flowchart



## 4.25 Program Suspend/Resume Procedure

| Bus Operation | Command         | Comments  |
|---------------|-----------------|---|
| Write         | Program Suspend | Data = B0<br>Addr = Any address   |
| Write         | Read Status     | Data = 70<br>Addr = Any address   |
| Read          | None            | Status register data: Toggle CE or OE to update status register<br>Addr = Any address |
| Idle          | None            | Check SR7<br>1 = WSM Ready<br>0 = WSM Busy  |
| Idle          | None            | Check SR2<br>1 = Program suspended<br>0 = Program completed                           |
| Write         | Read Array      | Data = FF<br>Addr = Any address   |
| Read          | None            | Read data from any word in the memory   |
| Write         | Program Resume  | Data = D0<br>Addr = Any address   |

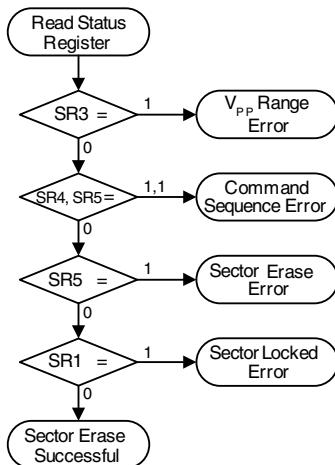
#### 4.26 Sector Erase Flowchart



#### 4.27 Sector Erase Procedure

| Bus Operation  | Command            | Comments   |
|--|--------------------|--|
| Write  | Sector Erase Setup | Data = 20<br>Addr = Any Address                                      |
| Write  | Erase Confirm      | Data = D0<br>Addr = Sector to be erased (SA)                         |
| Read   | None               | Status register data: Toggle CE or OE to update status register data |
| Idle   | None               | Check SR7<br>1 = WSMS Ready<br>0 = WSMS Busy                         |
| Repeat for subsequent sector erasures.<br>Full status register check can be done after each sector erase, or after a sequence of sector erasures.<br>Write FF after the last operation to enter read mode. |                    |  |

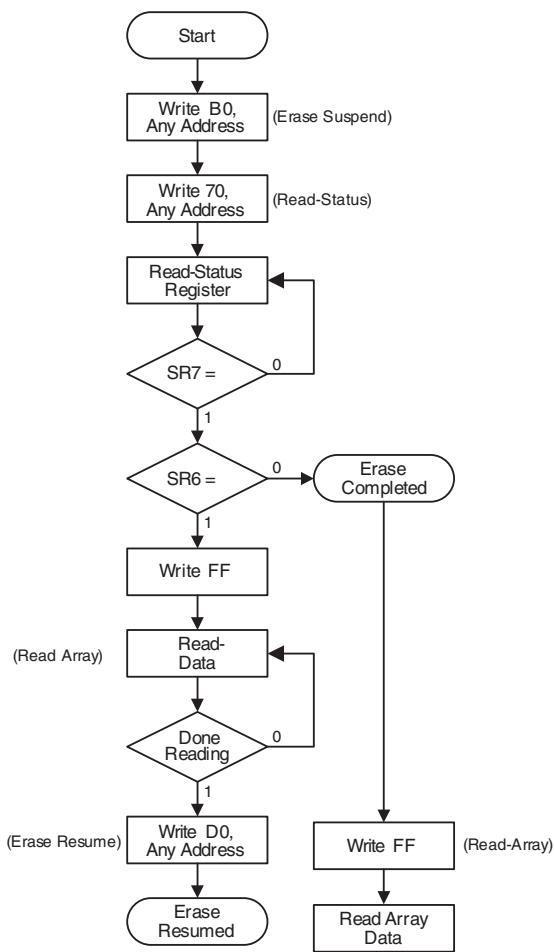
#### 4.28 Full Erase Status Check Flowchart



#### 4.29 Full Erase Status Check Procedure

| Bus Operation   | Command | Comments   |
|---|---------|--|
| Idle  | None    | Check SR3:<br>1 = V <sub>PP</sub> Range Error                      |
| Idle  | None    | Check SR4, SR5:<br>Both 1 = Command Sequence Error                 |
| Idle  | None    | Check SR5:<br>1 = Sector Erase Error                               |
| Idle  | None    | Check SR1:<br>1 = Attempted erase of locked sector; erase aborted. |
| SR1, SR3 must be cleared before the Write State Machine allows further erase attempts.<br>Only the Clear Status Register command clears SR1, SR3, SR4, SR5.<br>If an error is detected, clear the status register before attempting an erase retry or other error recovery. |         |  |

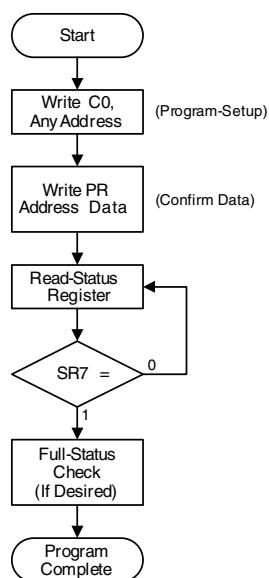
## 4.30 Erase Suspend/Resume Flowchart



## 4.31 Erase Suspend/Resume Procedure

| Bus Operation | Command         | Comments  |
|---------------|-----------------|---|
| Write         | Erase Suspend   | Data = B0<br>Addr = Any address   |
| Write         | Read Status     | Data = 70<br>Addr = Any address   |
| Read          | None            | Status register data: Toggle CE or OE to update status register<br>Addr = Any address |
| Idle          | None            | Check SR7<br>1 = WSM Ready<br>0 = WSM Busy  |
| Idle          | None            | Check SR6<br>1 = Erase suspended<br>0 = Erase completed                               |
| Write         | Read or Program | Data = FF or 40<br>Addr = Any address   |
| Read or Write | None            | Read or program data from/to sector other than the one being erased                   |
| Write         | Program Resume  | Data = D0<br>Addr = Any address   |

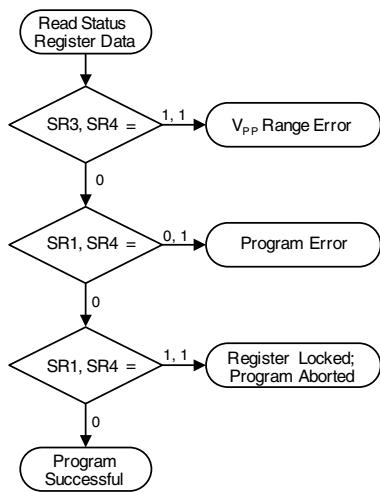
#### 4.32 Protection Register Programming Flowchart



#### 4.33 Protection Register Programming Procedure

| Bus Operation  | Command            | Comments   |
|--|--------------------|--|
| Write  | Program PR Setup   | Data = C0<br>Addr = Any Address                                      |
| Write  | Protection Program | Data = Data to Program<br>Addr = Location to Program                 |
| Read   | None               | Status register data: Toggle CE or OE to update status register data |
| Idle   | None               | Check SR7<br>1 = WSMS Ready<br>0 = WSMS Busy                         |
| <p>Program Protection Register operation addresses must be within the protection register address space. Addresses outside this space will return an error.</p> <p>Repeat for subsequent programming operations.</p> <p>Full status register check can be done after each program, or after a sequence of program operations.</p> <p>Write FF after the last operation to return to the Read mode.</p> |                    |  |

#### 4.34 Full Status Check Flowchart



#### 4.35 Full Status Check Procedure

| Bus Operation   | Command | Comments  |
|---|---------|---|
| Idle  | None    | Check SR1, SR3, SR4: 0,1,1 = V <sub>PP</sub> Range Error        |
| Idle  | None    | Check SR1, SR3, SR4: 0,0,1 = Programming Error                  |
| Idle  | None    | Check SR1, SR3, SR4: 1, 0, 1 = Sector locked; operation aborted |
| <p>SR3 must be cleared before the Write State Machine allows further program attempts.</p> <p>Only the Clear Status Register command clears SR1, SR3, SR4.</p> <p>If an error is detected, clear the status register before attempting a program retry or other error recovery.</p> |         |   |

## 5. Command Definition Table

| Command Sequence                                     | Bus Cycles | 1st Bus Cycle |       | 2nd Bus Cycle       |                                   | 3rd Bus Cycle |                  |
|--|------------|---------------|-------|---------------------|-----------------------------------|---------------|------------------|
|  |            | Addr          | Data  | Addr                | Data                              | Addr          | Data             |
| Read   | 1          | XX            | FF    |                     |                                   |               |                  |
| Sector Erase   | 2          | XX            | 20    | SA <sup>(2)</sup>   | D0                                |               |                  |
| Word Program   | 2          | XX            | 40/10 | Addr                | D <sub>IN</sub>                   |               |                  |
| Dual Word Program <sup>(3)</sup>                     | 3          | XX            | E0    | Addr0               | D <sub>IN0</sub>                  | Addr1         | D <sub>IN1</sub> |
| Erase/Program Suspend                                | 1          | XX            | B0    |                     |                                   |               |                  |
| Erase/Program Resume                                 | 1          | XX            | D0    |                     |                                   |               |                  |
| Product ID Entry <sup>(4)</sup>                      | 1          | XX            | 90    |                     |                                   |               |                  |
| Sector Softlock                                      | 2          | XX            | 60    | SA <sup>(2)</sup>   | 01                                |               |                  |
| Sector Unlock  | 2          | XX            | 60    | SA <sup>(2)</sup>   | D0                                |               |                  |
| Read Status Register                                 | 2          | XX            | 70    | XX                  | D <sub>OUT</sub> <sup>(5)</sup>   |               |                  |
| Clear Status Register                                | 1          | XX            | 50    |                     |                                   |               |                  |
| Program Protection Register (Block B)                | 2          | XX            | C0    | Addr <sup>(6)</sup> | D <sub>IN</sub>                   |               |                  |
| Lock Protection Register (Block B), Lock SCR7 - SCR0 | 2          | XX            | C0    | 80                  | D <sub>IN1</sub> <sup>(7)</sup>   |               |                  |
| Lock SCR23 - SCR8                                    | 2          | XX            | C0    | 79                  | D <sub>IN2</sub> <sup>(8)</sup>   |               |                  |
| Lock SCR37 - SCR24                                   | 2          | XX            | C0    | 78                  | D <sub>IN3</sub> <sup>(9)</sup>   |               |                  |
| Status of Protection Register (Block B), SCR7 - SCR0 | 2          | XX            | 90    | 80                  | D <sub>OUT1</sub> <sup>(10)</sup> |               |                  |
| Status of SCR23 - SCR8                               | 2          | XX            | 90    | 79                  | D <sub>OUT2</sub> <sup>(11)</sup> |               |                  |
| Status of SCR37 - SCR24                              | 2          | XX            | 90    | 78                  | D <sub>OUT3</sub> <sup>(12)</sup> |               |                  |
| CFI Query  | 1          | XX            | 98    |                     |                                   |               |                  |

Notes: 1. The DATA FORMAT shown for each bus cycle is as follows; I/O7 - I/O0 (Hex). I/O15 - I/O8 are don't care. The ADDRESS FORMAT shown for each bus cycle is as follows: A7 - A0 (Hex). Address A21 through A8 are don't care.

2. SA = sector address. Any word address within a sector can be used to designate the sector address (see pages 17 - 20 for details).
3. This fast programming option enables the user to program two words in parallel only when V<sub>PP</sub> = 9.5V. The addresses, Addr0 and Addr1, of the two words, D<sub>IN0</sub> and D<sub>IN1</sub>, must only differ in address A0. This command should be used during manufacturing purposes only.
4. During the second bus cycle, the manufacturer code is read from address 000000H, the device code is read from address 000001H, and the data in the protection register is read from addresses 000081H - 000088H.
5. The status register bits are output on I/O7 - I/O0.
6. Any address within the user programmable protection register region. Address locations are shown on the "Protection Register Addressing Table" on page 16.
7. D<sub>IN1</sub> represents 16 bits of data. If D1 is a "0", Protection Register (Block B) will be locked. If D9 - D2 is a "0", the corresponding region, SCR7 - SCR0, will be secure locked. If D10 is a "0" and bits D9 - D1 are all "1", the Freeze feature will be enabled. See Table 4-3 on page 7.
8. D<sub>IN2</sub> represents 16 bits of data. If D15 - D0 is a "0", the corresponding region, SCR23 - SCR8 will be secure locked. See Table 4-3 on page 7.
9. D<sub>IN3</sub> represents 16 bits of data. If D14 - D1 is a "0", the corresponding region SCR37 - SCR24 will be secure locked. See Table 4-3 on page 7.
10. If data bit D1 is "0", block B is locked. If data bit D1 is "1", block B can be reprogrammed. If data bit DX (X = 9 - 2) is "0", SCR (X - 2) is locked. If data bit DX is a "1", SCR (X - 2) can be reprogrammed. If bit D10 is a "0", the freeze feature is enabled.
11. If data bit DX (X = 15 - 0) is "0", SCR (X + 8) is locked. If data bit DX is a "1", SCR (X + 8) can be reprogrammed.
12. If data bit DX (X = 14 - 1) is "0", SCR (X + 23) is locked. If data bit DX is a "1" SCR (X + 23) can be reprogrammed.

## 6. Absolute Maximum Ratings\*

|   |                           |
|---|---------------------------|
| Temperature under Bias .....  | -55°C to +125°C           |
| Storage Temperature .....   | -65°C to +150°C           |
| All Input Voltages Except $V_{PP}$<br>(including NC Pins)<br>with Respect to Ground ..... | -0.6V to +6.25V           |
| All Output Voltages<br>with Respect to Ground .....                                       | -0.6V to $V_{CCQ} + 0.6V$ |
| $V_{PP}$ Input Voltage<br>with Respect to Ground .....                                    | -0.6V to 10.0V            |

\*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## 7. Protection Register Addressing Table

| Address | Use     | Block | A8 | A7 | A6 | A5 | A4 | A3 | A2 | A1 | A0 |
|---------|---------|-------|----|----|----|----|----|----|----|----|----|
| 81      | Factory | A     | 0  | 1  | 0  | 0  | 0  | 0  | 0  | 0  | 1  |
| 82      | Factory | A     | 0  | 1  | 0  | 0  | 0  | 0  | 0  | 1  | 0  |
| 83      | Factory | A     | 0  | 1  | 0  | 0  | 0  | 0  | 0  | 1  | 1  |
| 84      | Factory | A     | 0  | 1  | 0  | 0  | 0  | 0  | 1  | 0  | 0  |
| 85      | User    | B     | 0  | 1  | 0  | 0  | 0  | 0  | 1  | 0  | 1  |
| 86      | User    | B     | 0  | 1  | 0  | 0  | 0  | 0  | 1  | 1  | 0  |
| 87      | User    | B     | 0  | 1  | 0  | 0  | 0  | 0  | 1  | 1  | 1  |
| 88      | User    | B     | 0  | 1  | 0  | 0  | 0  | 1  | 0  | 0  | 0  |

Note: All address lines not specified in the above table must be "0" when accessing the protection register, i.e., A21 - A8 = 0.

## 8. Memory Organization – AT49BV640S

| Secure Region (SCR) | Sector | Size (Words) | x16 Address Range (A21 - A0) |
|---------------------|--------|--------------|------------------------------|
| 0                   | SA0    | 4K           | 00000 - 00FFF                |
|                     | SA1    | 4K           | 01000 - 01FFF                |
|                     | SA2    | 4K           | 02000 - 02FFF                |
|                     | SA3    | 4K           | 03000 - 03FFF                |
|                     | SA4    | 4K           | 04000 - 04FFF                |
|                     | SA5    | 4K           | 05000 - 05FFF                |
|                     | SA6    | 4K           | 06000 - 06FFF                |
|                     | SA7    | 4K           | 07000 - 07FFF                |
| 1                   | SA8    | 32K          | 08000 - 0FFFF                |
| 2                   | SA9    | 32K          | 10000 - 17FFF                |
| 3                   | SA10   | 32K          | 18000 - 1FFFF                |
| 4                   | SA11   | 32K          | 20000 - 27FFF                |
| 5                   | SA12   | 32K          | 28000 - 2FFFF                |
| 6                   | SA13   | 32K          | 30000 - 37FFF                |
| 7                   | SA14   | 32K          | 38000 - 3FFFF                |
| 8                   | SA15   | 32K          | 40000 - 47FFF                |
|                     | SA16   | 32K          | 48000 - 4FFFF                |
|                     | SA17   | 32K          | 50000 - 57FFF                |
|                     | SA18   | 32K          | 58000 - 5FFFF                |
| 9                   | SA19   | 32K          | 60000 - 67FFF                |
|                     | SA20   | 32K          | 68000 - 6FFFF                |
|                     | SA21   | 32K          | 70000 - 77FFF                |
|                     | SA22   | 32K          | 78000 - 7FFFF                |
| 10                  | SA23   | 32K          | 80000 - 87FFF                |
|                     | SA24   | 32K          | 88000 - 8FFFF                |
|                     | SA25   | 32K          | 90000 - 97FFF                |
|                     | SA26   | 32K          | 98000 - 9FFFF                |
| 11                  | SA27   | 32K          | A0000 - A7FFF                |
|                     | SA28   | 32K          | A8000 - AFFFF                |
|                     | SA29   | 32K          | B0000 - B7FFF                |
|                     | SA30   | 32K          | B8000 - BFFFF                |
| 12                  | SA31   | 32K          | C0000 - C7FFF                |
|                     | SA32   | 32K          | C8000 - CFFFF                |
|                     | SA33   | 32K          | D0000 - D7FFF                |
|                     | SA34   | 32K          | D8000 - DFFFF                |

## 8. Memory Organization – AT49BV640S (Continued)

| Secure Region (SCR) | Sector | Size (Words) | x16 Address Range (A21 - A0) |
|---------------------|--------|--------------|------------------------------|
| 13                  | SA35   | 32K          | E0000 - E7FFF                |
|                     | SA36   | 32K          | E8000 - EFFFF                |
|                     | SA37   | 32K          | F0000 - F7FFF                |
|                     | SA38   | 32K          | F8000 - FFFFF                |
| 14                  | SA39   | 32K          | 100000 - 107FFF              |
|                     | SA40   | 32K          | 108000 - 10FFFF              |
|                     | SA41   | 32K          | 110000 - 117FFF              |
|                     | SA42   | 32K          | 118000 - 11FFFF              |
| 15                  | SA43   | 32K          | 120000 - 127FFF              |
|                     | SA44   | 32K          | 128000 - 12FFFF              |
|                     | SA45   | 32K          | 130000 - 137FFF              |
|                     | SA46   | 32K          | 138000 - 13FFFF              |
| 16                  | SA47   | 32K          | 140000 - 147FFF              |
|                     | SA48   | 32K          | 148000 - 14FFFF              |
|                     | SA49   | 32K          | 150000 - 157FFF              |
|                     | SA50   | 32K          | 158000 - 15FFFF              |
| 17                  | SA51   | 32K          | 160000 - 167FFF              |
|                     | SA52   | 32K          | 168000 - 16FFFF              |
|                     | SA53   | 32K          | 170000 - 177FFF              |
|                     | SA54   | 32K          | 178000 - 17FFFF              |
| 18                  | SA55   | 32K          | 180000 - 187FFF              |
|                     | SA56   | 32K          | 188000 - 18FFFF              |
|                     | SA57   | 32K          | 190000 - 197FFF              |
|                     | SA58   | 32K          | 198000 - 19FFFF              |
| 19                  | SA59   | 32K          | 1A0000 - 1A7FFF              |
|                     | SA60   | 32K          | 1A8000 - 1AFFFF              |
|                     | SA61   | 32K          | 1B0000 - 1B7FFF              |
|                     | SA62   | 32K          | 1B8000 - 1BFFFF              |
| 20                  | SA63   | 32K          | 1C0000 - 1C7FFF              |
|                     | SA64   | 32K          | 1C8000 - 1CFFFF              |
|                     | SA65   | 32K          | 1D0000 - 1D7FFF              |
|                     | SA66   | 32K          | 1D8000 - 1DFFFF              |
| 21                  | SA67   | 32K          | 1E0000 - 1E7FFF              |
|                     | SA68   | 32K          | 1E8000 - 1EFFFF              |
|                     | SA69   | 32K          | 1F0000 - 1F7FFF              |
|                     | SA70   | 32K          | 1F8000 - 1FFFFFF             |

## 8. Memory Organization – AT49BV640S (Continued)

| Secure Region (SCR) | Sector | Size (Words) | x16 Address Range (A21 - A0) |
|---------------------|--------|--------------|------------------------------|
| 22                  | SA71   | 32K          | 200000 - 207FFF              |
|                     | SA72   | 32K          | 208000 - 20FFFF              |
|                     | SA73   | 32K          | 210000 - 217FFF              |
|                     | SA74   | 32K          | 218000 - 21FFFF              |
| 23                  | SA75   | 32K          | 220000 - 227FFF              |
|                     | SA76   | 32K          | 228000 - 22FFFF              |
|                     | SA77   | 32K          | 230000 - 237FFF              |
|                     | SA78   | 32K          | 238000 - 23FFFF              |
| 24                  | SA79   | 32K          | 240000 - 247FFF              |
|                     | SA80   | 32K          | 248000 - 24FFFF              |
|                     | SA81   | 32K          | 250000 - 257FFF              |
|                     | SA82   | 32K          | 258000 - 25FFFF              |
| 25                  | SA83   | 32K          | 260000 - 267FFF              |
|                     | SA84   | 32K          | 268000 - 26FFFF              |
|                     | SA85   | 32K          | 270000 - 277FFF              |
|                     | SA86   | 32K          | 278000 - 27FFFF              |
| 26                  | SA87   | 32K          | 280000 - 287FFF              |
|                     | SA88   | 32K          | 288000 - 28FFFF              |
|                     | SA89   | 32K          | 290000 - 297FFF              |
|                     | SA90   | 32K          | 298000 - 29FFFF              |
| 27                  | SA91   | 32K          | 2A0000 - 2A7FFF              |
|                     | SA92   | 32K          | 2A8000 - 2AFFFF              |
|                     | SA93   | 32K          | 2B0000 - 2B7FFF              |
|                     | SA94   | 32K          | 2B8000 - 2BFFFF              |
| 28                  | SA95   | 32K          | 2C0000 - 2C7FFF              |
|                     | SA96   | 32K          | 2C8000 - 2CFFFF              |
|                     | SA97   | 32K          | 2D0000 - 2D7FFF              |
|                     | SA98   | 32K          | 2D8000 - 2DFFFF              |
| 29                  | SA99   | 32K          | 2E0000 - 2E7FFF              |
|                     | SA100  | 32K          | 2E8000 - 2EFFFF              |
|                     | SA101  | 32K          | 2F0000 - 2F7FFF              |
|                     | SA102  | 32K          | 2F8000 - 2FFFFFF             |

## 8. Memory Organization – AT49BV640S (Continued)

| Secure Region (SCR) | Sector | Size (Words) | x16 Address Range (A21 - A0) |
|---------------------|--------|--------------|------------------------------|
| 30                  | SA103  | 32K          | 300000 - 307FFF              |
|                     | SA104  | 32K          | 308000 - 30FFFF              |
|                     | SA105  | 32K          | 310000 - 317FFF              |
|                     | SA106  | 32K          | 318000 - 31FFFF              |
| 31                  | SA107  | 32K          | 320000 - 327FFF              |
|                     | SA108  | 32K          | 328000 - 32FFFF              |
|                     | SA109  | 32K          | 330000 - 337FFF              |
|                     | SA110  | 32K          | 338000 - 33FFFF              |
| 32                  | SA111  | 32K          | 340000 - 347FFF              |
|                     | SA112  | 32K          | 348000 - 34FFFF              |
|                     | SA113  | 32K          | 350000 - 357FFF              |
|                     | SA114  | 32K          | 358000 - 35FFFF              |
| 33                  | SA115  | 32K          | 360000 - 367FFF              |
|                     | SA116  | 32K          | 368000 - 36FFFF              |
|                     | SA117  | 32K          | 370000 - 377FFF              |
|                     | SA118  | 32K          | 378000 - 37FFFF              |
| 34                  | SA119  | 32K          | 380000 - 387FFF              |
|                     | SA120  | 32K          | 388000 - 38FFFF              |
|                     | SA121  | 32K          | 390000 - 397FFF              |
|                     | SA122  | 32K          | 398000 - 39FFFF              |
| 35                  | SA123  | 32K          | 3A0000 - 3A7FFF              |
|                     | SA124  | 32K          | 3A8000 - 3AFFFF              |
|                     | SA125  | 32K          | 3B0000 - 3B7FFF              |
|                     | SA126  | 32K          | 3B8000 - 3BFFFF              |
| 36                  | SA127  | 32K          | 3C0000 - 3C7FFF              |
|                     | SA128  | 32K          | 3C8000 - 3CFFFF              |
|                     | SA129  | 32K          | 3D0000 - 3D7FFF              |
|                     | SA130  | 32K          | 3D8000 - 3DFFFF              |
| 37                  | SA131  | 32K          | 3E0000 - 3E7FFF              |
|                     | SA132  | 32K          | 3E8000 - 3EFFFF              |
|                     | SA133  | 32K          | 3F0000 - 3F7FFF              |
|                     | SA134  | 32K          | 3F8000 - 3FFFFFF             |

## 9. Memory Organization – AT49BV640ST

| Secure Region (SCR) | Sector | Size (Words) | x16 Address Range (A21 - A0) |
|---------------------|--------|--------------|------------------------------|
| 37                  | SA0    | 32K          | 00000 - 07FFF                |
|                     | SA1    | 32K          | 08000 - 0FFFF                |
|                     | SA2    | 32K          | 10000 - 17FFF                |
|                     | SA3    | 32K          | 18000 - 1FFFF                |
| 36                  | SA4    | 32K          | 20000 - 27FFF                |
|                     | SA5    | 32K          | 28000 - 2FFFF                |
|                     | SA6    | 32K          | 30000 - 37FFF                |
|                     | SA7    | 32K          | 38000 - 3FFFF                |
| 35                  | SA8    | 32K          | 40000 - 47FFF                |
|                     | SA9    | 32K          | 48000 - 4FFFF                |
|                     | SA10   | 32K          | 50000 - 57FFF                |
|                     | SA11   | 32K          | 58000 - 5FFFF                |
| 34                  | SA12   | 32K          | 60000 - 67FFF                |
|                     | SA13   | 32K          | 68000 - 6FFFF                |
|                     | SA14   | 32K          | 70000 - 77FFF                |
|                     | SA15   | 32K          | 78000 - 7FFFF                |
| 33                  | SA16   | 32K          | 80000 - 87FFF                |
|                     | SA17   | 32K          | 88000 - 8FFFF                |
|                     | SA18   | 32K          | 90000 - 97FFF                |
|                     | SA19   | 32K          | 98000 - 9FFFF                |
| 32                  | SA20   | 32K          | A0000 - A7FFF                |
|                     | SA21   | 32K          | A8000 - AFFFF                |
|                     | SA22   | 32K          | B0000 - B7FFF                |
|                     | SA23   | 32K          | B8000 - BFFFF                |
| 31                  | SA24   | 32K          | C0000 - C7FFF                |
|                     | SA25   | 32K          | C8000 - CFFFF                |
|                     | SA26   | 32K          | D0000 - D7FFF                |
|                     | SA27   | 32K          | D8000 - DFFFF                |
| 30                  | SA28   | 32K          | E0000 - E7FFF                |
|                     | SA29   | 32K          | E8000 - EFFFF                |
|                     | SA30   | 32K          | F0000 - F7FFF                |
|                     | SA31   | 32K          | F8000 - FFFFF                |
| 29                  | SA32   | 32K          | 100000 - 107FFF              |
|                     | SA33   | 32K          | 108000 - 10FFFF              |
|                     | SA34   | 32K          | 110000 - 117FFF              |
|                     | SA35   | 32K          | 118000 - 11FFFF              |

## 9. Memory Organization – AT49BV640ST (Continued)

| Secure Region (SCR) | Sector | Size (Words) | x16 Address Range (A21 - A0) |
|---------------------|--------|--------------|------------------------------|
| 28                  | SA36   | 32K          | 120000 - 127FFF              |
|                     | SA37   | 32K          | 128000 - 12FFFF              |
|                     | SA38   | 32K          | 130000 - 137FFF              |
|                     | SA39   | 32K          | 138000 - 13FFFF              |
| 27                  | SA40   | 32K          | 140000 - 147FFF              |
|                     | SA41   | 32K          | 148000 - 14FFFF              |
|                     | SA42   | 32K          | 150000 - 157FFF              |
|                     | SA43   | 32K          | 158000 - 15FFFF              |
| 26                  | SA44   | 32K          | 160000 - 167FFF              |
|                     | SA45   | 32K          | 168000 - 16FFFF              |
|                     | SA46   | 32K          | 170000 - 177FFF              |
|                     | SA47   | 32K          | 178000 - 17FFFF              |
| 25                  | SA48   | 32K          | 180000 - 187FFF              |
|                     | SA49   | 32K          | 188000 - 18FFFF              |
|                     | SA50   | 32K          | 190000 - 197FFF              |
|                     | SA51   | 32K          | 198000 - 19FFFF              |
| 24                  | SA52   | 32K          | 1A0000 - 1A7FFF              |
|                     | SA53   | 32K          | 1A8000 - 1AFFFF              |
|                     | SA54   | 32K          | 1B0000 - 1B7FFF              |
|                     | SA55   | 32K          | 1B8000 - 1BFFFF              |
| 23                  | SA56   | 32K          | 1C0000 - 1C7FFF              |
|                     | SA57   | 32K          | 1C8000 - 1CFFFF              |
|                     | SA58   | 32K          | 1D0000 - 1D7FFF              |
|                     | SA59   | 32K          | 1D8000 - 1DFFFF              |
| 22                  | SA60   | 32K          | 1E0000 - 1E7FFF              |
|                     | SA61   | 32K          | 1E8000 - 1EFFFF              |
|                     | SA62   | 32K          | 1F0000 - 1F7FFF              |
|                     | SA63   | 32K          | 1F8000 - 1FFFFFF             |
| 21                  | SA64   | 32K          | 200000 - 207FFF              |
|                     | SA65   | 32K          | 208000 - 20FFFF              |
|                     | SA66   | 32K          | 210000 - 217FFF              |
|                     | SA67   | 32K          | 218000 - 21FFFF              |
| 20                  | SA68   | 32K          | 220000 - 227FFF              |
|                     | SA69   | 32K          | 228000 - 22FFFF              |
|                     | SA70   | 32K          | 230000 - 237FFF              |
|                     | SA71   | 32K          | 238000 - 23FFFF              |

## 9. Memory Organization – AT49BV640ST (Continued)

| Secure Region (SCR) | Sector | Size (Words) | x16 Address Range (A21 - A0) |
|---------------------|--------|--------------|------------------------------|
| 19                  | SA72   | 32K          | 240000 - 247FFF              |
|                     | SA73   | 32K          | 248000 - 24FFFF              |
|                     | SA74   | 32K          | 250000 - 257FFF              |
|                     | SA75   | 32K          | 258000 - 25FFFF              |
| 18                  | SA76   | 32K          | 260000 - 267FFF              |
|                     | SA77   | 32K          | 268000 - 26FFFF              |
|                     | SA78   | 32K          | 270000 - 277FFF              |
|                     | SA79   | 32K          | 278000 - 27FFFF              |
| 17                  | SA80   | 32K          | 280000 - 287FFF              |
|                     | SA81   | 32K          | 288000 - 28FFFF              |
|                     | SA82   | 32K          | 290000 - 297FFF              |
|                     | SA83   | 32K          | 298000 - 29FFFF              |
| 16                  | SA84   | 32K          | 2A0000 - 2A7FFF              |
|                     | SA85   | 32K          | 2A8000 - 2AFFFF              |
|                     | SA86   | 32K          | 2B0000 - 2B7FFF              |
|                     | SA87   | 32K          | 2B8000 - 2BFFFF              |
| 15                  | SA88   | 32K          | 2C0000 - 2C7FFF              |
|                     | SA89   | 32K          | 2C8000 - 2CFFFF              |
|                     | SA90   | 32K          | 2D0000 - 2D7FFF              |
|                     | SA91   | 32K          | 2D8000 - 2DFFFF              |
| 14                  | SA92   | 32K          | 2E0000 - 2E7FFF              |
|                     | SA93   | 32K          | 2E8000 - 2EFFFF              |
|                     | SA94   | 32K          | 2F0000 - 2F7FFF              |
|                     | SA95   | 32K          | 2F8000 - 2FFFFF              |
| 13                  | SA96   | 32K          | 300000 - 307FFF              |
|                     | SA97   | 32K          | 308000 - 30FFFF              |
|                     | SA98   | 32K          | 310000 - 317FFF              |
|                     | SA99   | 32K          | 318000 - 31FFFF              |
| 12                  | SA100  | 32K          | 320000 - 327FFF              |
|                     | SA101  | 32K          | 328000 - 32FFFF              |
|                     | SA102  | 32K          | 330000 - 337FFF              |
|                     | SA103  | 32K          | 338000 - 33FFFF              |

## 9. Memory Organization – AT49BV640ST (Continued)

| Secure Region (SCR) | Sector | Size (Words) | x16 Address Range (A21 - A0) |
|---------------------|--------|--------------|------------------------------|
| 11                  | SA104  | 32K          | 340000 - 347FFF              |
|                     | SA105  | 32K          | 348000 - 34FFFF              |
|                     | SA106  | 32K          | 350000 - 357FFF              |
|                     | SA107  | 32K          | 358000 - 35FFFF              |
| 10                  | SA108  | 32K          | 360000 - 367FFF              |
|                     | SA109  | 32K          | 368000 - 36FFFF              |
|                     | SA110  | 32K          | 370000 - 377FFF              |
|                     | SA111  | 32K          | 378000 - 37FFFF              |
| 9                   | SA112  | 32K          | 380000 - 387FFF              |
|                     | SA113  | 32K          | 388000 - 38FFFF              |
|                     | SA114  | 32K          | 390000 - 397FFF              |
|                     | SA115  | 32K          | 398000 - 39FFFF              |
| 8                   | SA116  | 32K          | 3A0000 - 3A7FFF              |
|                     | SA117  | 32K          | 3A8000 - 3AFFFF              |
|                     | SA118  | 32K          | 3B0000 - 3B7FFF              |
|                     | SA119  | 32K          | 3B8000 - 3BFFFF              |
| 7                   | SA120  | 32K          | 3C0000 - 3C7FFF              |
| 6                   | SA121  | 32K          | 3C8000 - 3CFFFF              |
| 5                   | SA122  | 32K          | 3D0000 - 3D7FFF              |
| 4                   | SA123  | 32K          | 3D8000 - 3DFFFF              |
| 3                   | SA124  | 32K          | 3E0000 - 3E7FFF              |
| 2                   | SA125  | 32K          | 3E8000 - 3EFFFF              |
| 1                   | SA126  | 32K          | 3F0000 - 3F7FFF              |
| 0                   | SA127  | 4K           | 3F8000 - 3F8FFF              |
|                     | SA128  | 4K           | 3F9000 - 3F9FFF              |
|                     | SA129  | 4K           | 3FA000 - 3FAFFF              |
|                     | SA130  | 4K           | 3FB000 - 3FBFFF              |
|                     | SA131  | 4K           | 3FC000 - 3FCFFF              |
|                     | SA132  | 4K           | 3FD000 - 3FDFFF              |
|                     | SA133  | 4K           | 3FE000 - 3FEFFF              |
|                     | SA134  | 4K           | 3FF000 - 3FFFFF              |

## 10. DC and AC Operating Range

|                              |  |            |  | AT49BV640S(T)-70 |
|------------------------------|--|------------|--|------------------|
| Operating Temperature (Case) |  | Industrial |  | -40°C - 85°C     |
| $V_{CC}$ Power Supply        |  |            |  | 2.65V - 3.6V     |

## 11. Operating Modes

| Mode                            | $\overline{CE}$ | $\overline{OE}$ | $\overline{WE}$ | $\overline{RESET}$ | $V_{PP}^{(1)}$   | $A_i$                              | I/O                              |
|---------------------------------|-----------------|-----------------|-----------------|--------------------|------------------|------------------------------------|----------------------------------|
| Read                            | $V_{IL}$        | $V_{IL}$        | $V_{IH}$        | $V_{IH}$           | $X^{(2)}$        | $A_i$                              | $D_{OUT}$                        |
| Program/Erase <sup>(3)</sup>    | $V_{IL}$        | $V_{IH}$        | $V_{IL}$        | $V_{IH}$           | $V_{IHPP}^{(4)}$ | $A_i$                              | $D_{IN}$                         |
| Standby/Program Inhibit         | $V_{IH}$        | $X^{(2)}$       | X               | $V_{IH}$           | X                | X                                  | High Z                           |
| Program Inhibit                 | X               | X               | $V_{IH}$        | $V_{IH}$           | X                |                                    |                                  |
|                                 | X               | $V_{IL}$        | X               | $V_{IH}$           | X                |                                    |                                  |
|                                 | X               | X               | X               | X                  | $V_{ILPP}^{(5)}$ |                                    |                                  |
| Output Disable                  | X               | $V_{IH}$        | X               | $V_{IH}$           | X                |                                    | High Z                           |
| Reset                           | X               | X               | X               | $V_{IL}$           | X                | X                                  | High Z                           |
| Product Identification Software |                 |                 |                 | $V_{IH}$           |                  | $A_0 = V_{IL}, A_1 - A21 = V_{IL}$ | Manufacturer Code <sup>(6)</sup> |
|                                 |                 |                 |                 |                    |                  | $A_0 = V_{IH}, A_1 - A21 = V_{IL}$ | Device Code <sup>(6)</sup>       |

Notes: 1. The VPP pin can be tied to  $V_{CC}$ . For faster program operation,  $V_{PP}$  can be set to 9.5V ± 0.5V.

2. X can be VIL or VIH.
3. Refer to AC programming waveforms on [page 25](#).
4.  $V_{IHPP}$  (min) = 1.65V.
5.  $V_{ILPP}$  (max) = 0.4V.
6. Manufacturer Code: 001FH; Device Code: 02DEH – AT49BV640S; 02DBH – AT49BV640ST

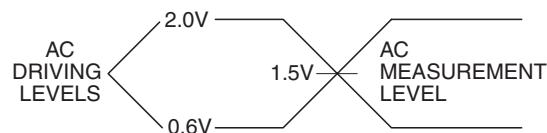
## 12. DC Characteristics

| Symbol         | Parameter                     | Condition                                    | Min             | Typ | Max  | Units   |
|----------------|-------------------------------|--|-----------------|-----|------|---------|
| $I_{LI}$       | Input Load Current            | $V_{IN} = 0V$ to $V_{CC}$                    |                 |     | 2    | $\mu A$ |
| $I_{LO}$       | Output Leakage Current        | $V_{I/O} = 0V$ to $V_{CC}$                   |                 |     | 2    | $\mu A$ |
| $I_{SB}$       | $V_{CC}$ Standby Current CMOS | $\overline{CE} = V_{CCQ} - 0.3V$ to $V_{CC}$ |                 | 15  | 25   | $\mu A$ |
| $I_{CC}^{(1)}$ | $V_{CC}$ Active Read Current  | $f = 5$ MHz; $I_{OUT} = 0$ mA                |                 | 10  | 15   | mA      |
| $I_{CC1}$      | $V_{CC}$ Programming Current  |  |                 |     | 25   | mA      |
| $I_{PP1}$      | $V_{PP}$ Input Load Current   |  |                 |     | 10   | $\mu A$ |
| $V_{IL}$       | Input Low Voltage             |  |                 |     | 0.6  | V       |
| $V_{IH}$       | Input High Voltage            |  | $V_{CCQ} - 0.6$ |     |      | V       |
| $V_{OL}$       | Output Low Voltage            | $I_{OL} = 2.1$ mA                            |                 |     | 0.45 | V       |
| $V_{OH}$       | Output High Voltage           | $I_{OH} = -100$ $\mu A$                      | $V_{CCQ} - 0.1$ |     |      | V       |

Note: 1. In the erase mode,  $I_{CC}$  is 25 mA.

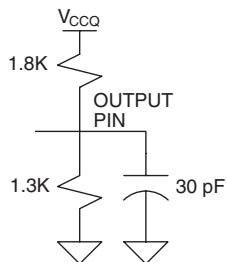


## 13. Input Test Waveforms and Measurement Level



$t_R, t_F < 5 \text{ ns}$

## 14. Output Test Load



## 15. Pin Capacitance

$f = 1 \text{ MHz}, T = 25^\circ\text{C}$  <sup>(1)</sup>

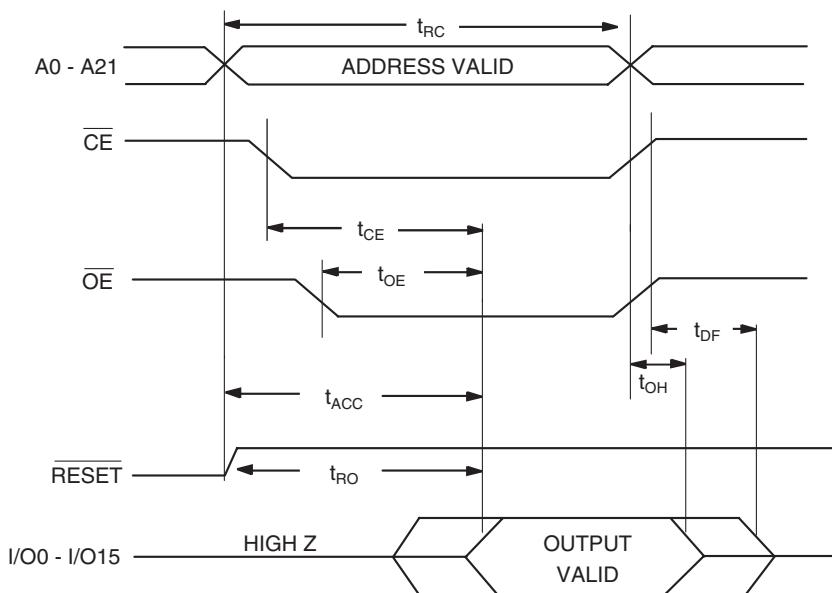
|           | Typ | Max | Units | Conditions     |
|-----------|-----|-----|-------|----------------|
| $C_{IN}$  | 4   | 6   | pF    | $V_{IN} = 0V$  |
| $C_{OUT}$ | 8   | 12  | pF    | $V_{OUT} = 0V$ |

Note: 1. This parameter is characterized and is not 100% tested.

## 16. AC Read Characteristics

| Symbol            | Parameter   | AT49BV640S(T)-70 |     |       |
|-------------------|---|------------------|-----|-------|
|                   |   | Min              | Max | Units |
| $t_{RC}$          | Read Cycle Time   | 70               |     | ns    |
| $t_{ACC}$         | Access, Address to Data Valid   |                  | 70  | ns    |
| $t_{CE}^{(1)}$    | Access, $\overline{CE}$ to Data Valid   |                  | 70  | ns    |
| $t_{OE}^{(2)}$    | $\overline{OE}$ to Data Valid   |                  | 20  | ns    |
| $t_{DF}^{(3)(4)}$ | $\overline{CE}$ , $\overline{OE}$ High to Data Float                                  |                  | 25  | ns    |
| $t_{OH}$          | Output Hold from $\overline{OE}$ , $\overline{CE}$ or Address, whichever Occurs First | 0                |     | ns    |
| $t_{RO}$          | $\overline{RESET}$ to Output Delay  |                  | 100 | ns    |

## 17. Asynchronous Read Cycle Waveform <sup>(1)(2)(3)(4)</sup>



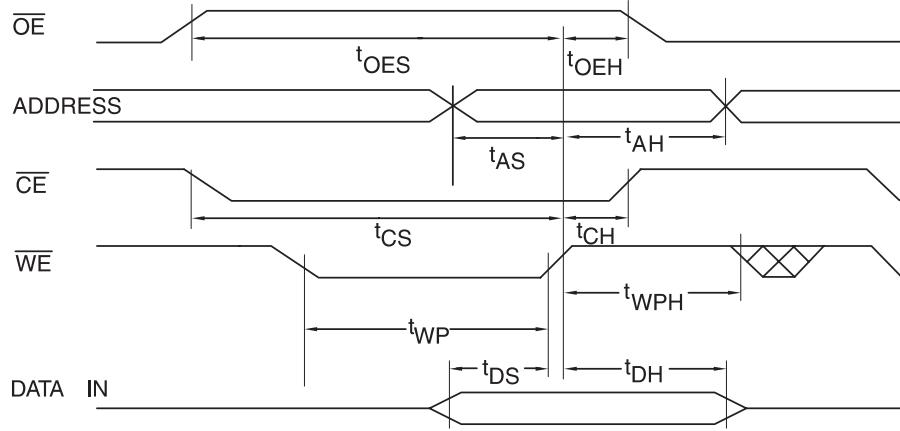
- Notes:
1.  $\overline{CE}$  may be delayed up to  $t_{ACC} - t_{CE}$  after the address transition without impact on  $t_{ACC}$ .
  2.  $\overline{OE}$  may be delayed up to  $t_{CE} - t_{OE}$  after the falling edge of  $\overline{CE}$  without impact on  $t_{CE}$  or by  $t_{ACC} - t_{OE}$  after an address change without impact on  $t_{ACC}$ .
  3.  $t_{DF}$  is specified from  $\overline{OE}$  or  $\overline{CE}$ , whichever occurs first (CL = 5 pF).
  4. This parameter is characterized and is not 100% tested.

## 18. AC Word Load Characteristics

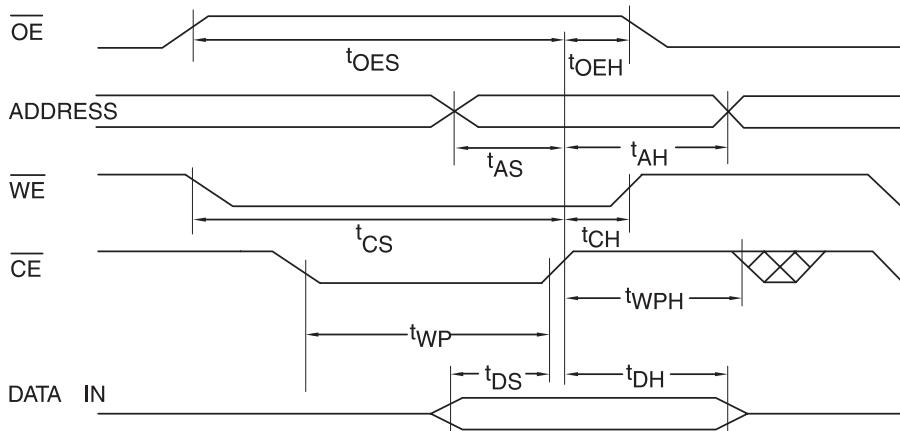
| Symbol            | Parameter  | Min | Max | Units |
|-------------------|--|-----|-----|-------|
| $t_{AS}, t_{OES}$ | Address, $\overline{OE}$ Setup Time                      | 20  |     | ns    |
| $t_{AH}$          | Address Hold Time  | 0   |     | ns    |
| $t_{CS}$          | Chip Select Setup Time                                   | 0   |     | ns    |
| $t_{CH}$          | Chip Select Hold Time                                    | 0   |     | ns    |
| $t_{WP}$          | Write Pulse Width ( $\overline{WE}$ or $\overline{CE}$ ) | 25  |     | ns    |
| $t_{WPH}$         | Write Pulse Width High                                   | 15  |     | ns    |
| $t_{DS}$          | Data Setup Time  | 25  |     | ns    |
| $t_{DH}, t_{OEH}$ | Data, $\overline{OE}$ Hold Time                          | 0   |     | ns    |

## 19. AC Word Load Waveforms

### 19.1 $\overline{WE}$ Controlled



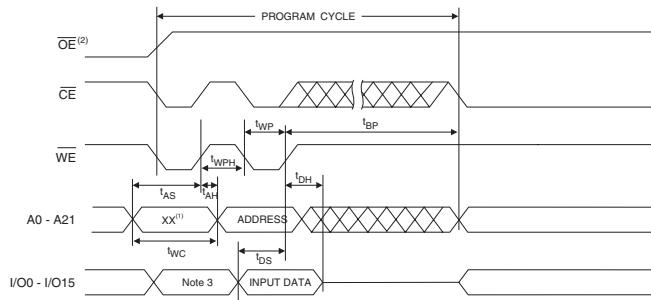
### 19.2 $\overline{CE}$ Controlled



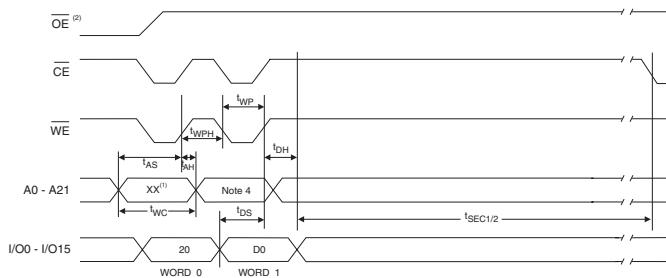
## 20. Program Cycle Characteristics

| Symbol     | Parameter                                      | Min | Typ | Max | Units   |
|------------|--|-----|-----|-----|---------|
| $t_{BP}$   | Word Programming Time                          |     | 10  | 120 | $\mu s$ |
| $t_{BPD}$  | Word Programming Time in Dual Programming Mode |     | 5   | 60  | $\mu s$ |
| $t_{AS}$   | Address Setup Time                             | 20  |     |     | ns      |
| $t_{AH}$   | Address Hold Time                              | 0   |     |     | ns      |
| $t_{DS}$   | Data Setup Time                                | 25  |     |     | ns      |
| $t_{DH}$   | Data Hold Time                                 | 0   |     |     | ns      |
| $t_{WP}$   | Write Pulse Width                              | 25  |     |     | ns      |
| $t_{WPH}$  | Write Pulse Width High                         | 15  |     |     | ns      |
| $t_{WC}$   | Write Cycle Time                               | 70  |     |     | ns      |
| $t_{RP}$   | Reset Pulse Width                              | 500 |     |     | ns      |
| $t_{SEC1}$ | Sector Erase Cycle Time (4K Word Sectors)      |     | 0.1 | 2.0 | seconds |
| $t_{SEC2}$ | Sector Erase Cycle Time (32K Word Sectors)     |     | 0.5 | 6.0 | seconds |
| $t_{ES}$   | Erase Suspend Time                             |     |     | 15  | $\mu s$ |
| $t_{PS}$   | Program Suspend Time                           |     |     | 10  | $\mu s$ |
| $t_{ERES}$ | Delay between Erase Resume and Erase Suspend   | 500 |     |     | $\mu s$ |

## 21. Program Cycle Waveforms



## 22. Sector Erase Cycle Waveforms



- Notes:
1. Any address can be used to load data.
  2.  $\overline{OE}$  must be high only when  $\overline{WE}$  and  $\overline{CE}$  are both low.
  3. The data can be 40H or 10H.
  4. The address depends on what sector is to be erased.

## 23. Common Flash Interface Definition Table

| Address | AT49BV640ST | AT49BV640S | Comments  |
|---------|-------------|------------|---|
| 10h     | 0051h       | 0051h      | "Q"   |
| 11h     | 0052h       | 0052h      | "R"   |
| 12h     | 0059h       | 0059h      | "Y"   |
| 13h     | 0003h       | 0003h      |   |
| 14h     | 0000h       | 0000h      |   |
| 15h     | 0041h       | 0041h      |   |
| 16h     | 0000h       | 0000h      |   |
| 17h     | 0000h       | 0000h      |   |
| 18h     | 0000h       | 0000h      |   |
| 19h     | 0000h       | 0000h      |   |
| 1Ah     | 0000h       | 0000h      |   |
| 1Bh     | 0027h       | 0027h      | VCC min write/erase                                 |
| 1Ch     | 0036h       | 0036h      | VCC max write/erase                                 |
| 1Dh     | 0090h       | 0090h      | VPP min voltage                                     |
| 1Eh     | 00A0h       | 00A0h      | VPP max voltage                                     |
| 1Fh     | 0004h       | 0004h      | Typ word write – 10 µs                              |
| 20h     | 0002h       | 0002h      | Typ dual word program time – 5 µs                   |
| 21h     | 0009h       | 0009h      | Typ sector erase – 700 ms                           |
| 22h     | 0000h       | 0000h      | Typ chip erase – N/A                                |
| 23h     | 0004h       | 0004h      | Max word write/typ time                             |
| 24h     | 0004h       | 0004h      | Max dual word program time/typical time             |
| 25h     | 0003h       | 0003h      | Max sector erase/typ sector erase                   |
| 26h     | 0000h       | 0000h      | Max chip erase/ typ chip erase – N/A                |
| 27h     | 0017h       | 0017h      | Device size   |
| 28h     | 0001h       | 0001h      | x16 device  |
| 29h     | 0000h       | 0000h      | x16 device  |
| 2Ah     | 0002h       | 0002h      | Maximum number of bytes in multiple byte write = 4  |
| 2Bh     | 0000h       | 0000h      | Maximum number of bytes in multiple byte write = 4  |
| 2Ch     | 0002h       | 0002h      | 2 regions, x = 2                                    |
| 2Dh     | 007Eh       | 0007h      | 64K bytes, Y = 126 (Top); 8K bytes, Y = 7 (Bottom)  |
| 2Eh     | 0000h       | 0000h      | 64K bytes, Y = 126 (Top); 8K bytes, Y = 7 (Bottom)  |
| 2Fh     | 0000h       | 0020h      | 64K bytes, Z = 256 (Top); 8K bytes, Z = 32 (Bottom) |
| 30h     | 0001h       | 0000h      | 64K bytes, Z = 256 (Top); 8K bytes, Z = 32 (Bottom) |
| 31h     | 0007h       | 007Eh      | 8K bytes, Y = 7 (Top); 64K bytes, Y = 126 (Bottom)  |
| 32h     | 0000h       | 0000h      | 8K bytes, Y = 7 (Top); 64K bytes, Y = 126 (Bottom)  |
| 33h     | 0020h       | 0000h      | 8K bytes, Z = 32 (Top); 64K bytes, Z = 256 (Bottom) |
| 34h     | 0000h       | 0001h      | 8K bytes, Z = 32 (Top); 64K bytes, Z = 256 (Bottom) |

### 23. Common Flash Interface Definition Table (Continued)

| Address                               | AT49BV640ST | AT49BV640S | Comments  |
|---------------------------------------|-------------|------------|---|
| <b>VENDOR SPECIFIC EXTENDED QUERY</b> |             |            |   |
| 41h                                   | 0050h       | 0050h      | "P"   |
| 42h                                   | 0052h       | 0052h      | "R"   |
| 43h                                   | 0049h       | 0049h      | "I"   |
| 44h                                   | 0031h       | 0031h      | Major version number, ASCII   |
| 45h                                   | 0030h       | 0030h      | Minor version number, ASCII   |
| 46h                                   | 0086h       | 0086h      | Bit 0 – chip erase supported, 0 – no, 1 – yes<br>Bit 1 – erase suspend supported, 0 – no, 1 – yes<br>Bit 2 – program suspend supported, 0 – no, 1 – yes<br>Bit 3 – simultaneous operations supported, 0 – no, 1 – yes<br>Bit 4 – burst mode read supported, 0 – no, 1 – yes<br>Bit 5 – page mode read supported, 0 – no, 1 – yes<br>Bit 6 – queued erase supported, 0 – no, 1 – yes<br>Bit 7 – protection bits supported, 0 – no, 1 – yes |
| 47h                                   | 0000h       | 0001h      | Bit 0 – top ("0") or bottom ("1") boot block device<br>Undefined bits are "0"   |
| 48h                                   | 0000h       | 0000h      | Bit 0 – 4 word linear burst with wrap around, 0 – no, 1 – yes<br>Bit 1 – 8 word linear burst with wrap around, 0 – no, 1 – yes<br>Bit 2 – 16 word linear burst with wrap around, 0 – no, 1 – yes<br>Bit 3 – continuous burst, 0 – no, 1 – yes<br>Undefined bits are "0"   |
| 49h                                   | 0000h       | 0000h      | Bit 0 – 4 word page, 0 – no, 1 – yes<br>Bit 1 – 8 word page, 0 – no, 1 – yes<br>Undefined bits are "0"  |
| 4Ah                                   | 0080h       | 0080h      | Location of protection register lock byte, the section's first byte   |
| 4Bh                                   | 0003h       | 0003h      | # of bytes in the factory prog section of prot register – 2*n   |
| 4Ch                                   | 0003h       | 0003h      | # of bytes in the user prog section of prot register – 2*n  |

## 24. Ordering Information

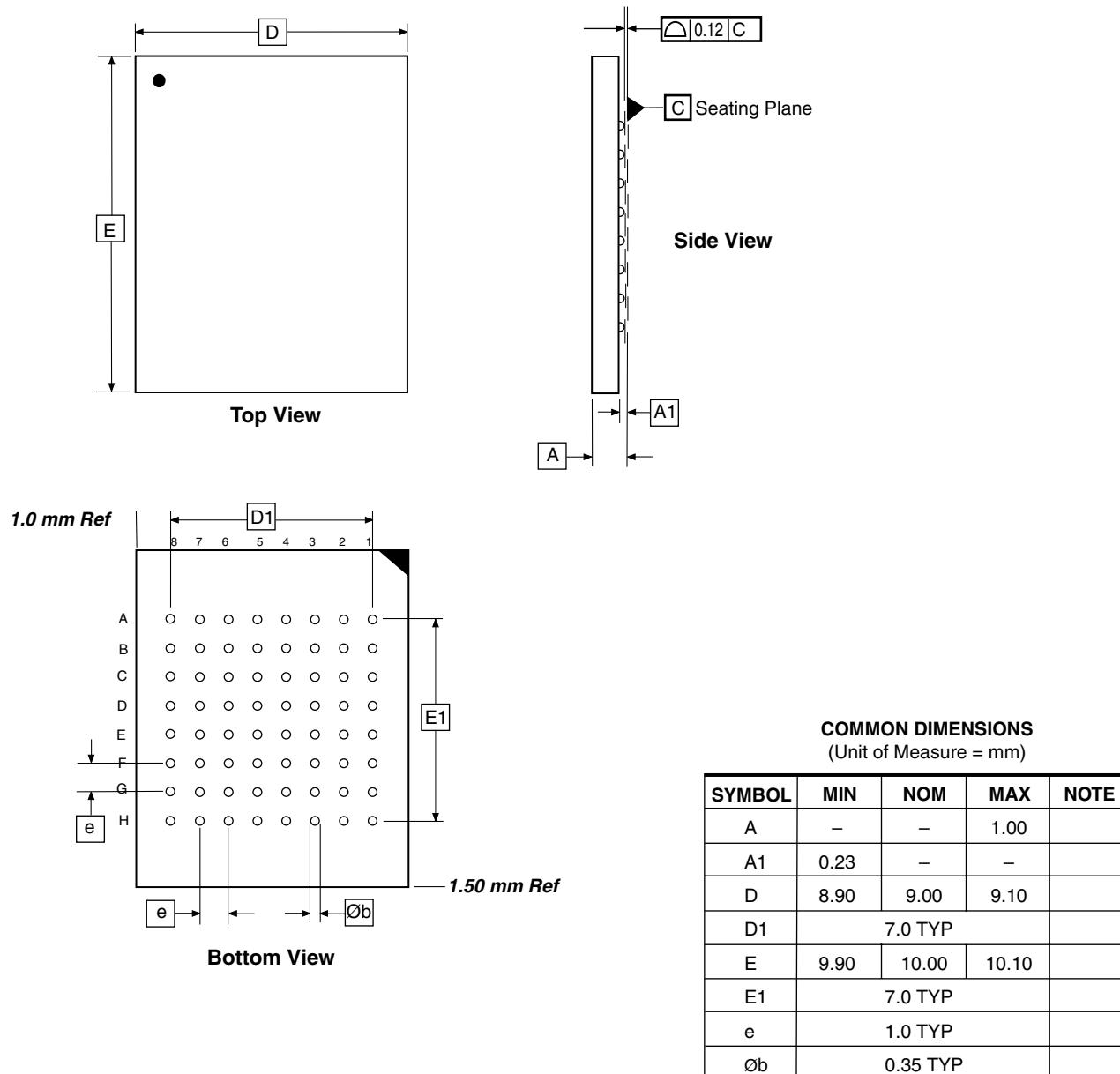
### 24.1 Green Package (Pb/Halide-free/RoHS Compliant)

| t <sub>ACC</sub><br>(ns) | I <sub>CC</sub> (mA) |         | Ordering Code    | Package | Operation Range               |
|--------------------------|----------------------|---------|------------------|---------|-------------------------------|
|                          | Active               | Standby |                  |         |                               |
| 70                       | 10                   | 0.025   | AT49BV640S-70CU  | 64C1    | Industrial<br>(-40° to 85° C) |
|                          |                      |         | AT49BV640ST-70CU |         |                               |

| Package Type |   |
|--------------|---|
| 64C1         | 64-ball, Plastic Chip-size Ball Grid Array Package (CBGA) |

## 25. Packaging Information

### 25.1 64C1 – CBGA



1/25/05

|  |   |                            |                  |
|--|---|----------------------------|------------------|
| <b>ATMEL</b><br>2325 Orchard Parkway<br>San Jose, CA 95131 | <b>TITLE</b><br><b>64C1, 64-ball (8 x 8 Array), 9 x 10 x 1.0 mm Body, 1.0 mm Ball Pitch Chip-scale Ball Grid Array Package (CBGA)</b> | <b>DRAWING NO.</b><br>64C1 | <b>REV.</b><br>B |
|--|---|----------------------------|------------------|



## Atmel Corporation

2325 Orchard Parkway  
San Jose, CA 95131, USA  
Tel: 1(408) 441-0311  
Fax: 1(408) 487-2600

## Regional Headquarters

### Europe

Atmel Sarl  
Route des Arsenaux 41  
Case Postale 80  
CH-1705 Fribourg  
Switzerland  
Tel: (41) 26-426-5555  
Fax: (41) 26-426-5500

### Asia

Room 1219  
Chinachem Golden Plaza  
77 Mody Road Tsimshatsui  
East Kowloon  
Hong Kong  
Tel: (852) 2721-9778  
Fax: (852) 2722-1369

### Japan

9F, Tonetsu Shinkawa Bldg.  
1-24-8 Shinkawa  
Chuo-ku, Tokyo 104-0033  
Japan  
Tel: (81) 3-3523-3551  
Fax: (81) 3-3523-7581

## Atmel Operations

### Memory

2325 Orchard Parkway  
San Jose, CA 95131, USA  
Tel: 1(408) 441-0311  
Fax: 1(408) 436-4314

### Microcontrollers

2325 Orchard Parkway  
San Jose, CA 95131, USA  
Tel: 1(408) 441-0311  
Fax: 1(408) 436-4314

La Chantrerie  
BP 70602  
44306 Nantes Cedex 3, France  
Tel: (33) 2-40-18-18-18  
Fax: (33) 2-40-18-19-60

### ASIC/ASSP/Smart Cards

Zone Industrielle  
13106 Rousset Cedex, France  
Tel: (33) 4-42-53-60-00  
Fax: (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd.  
Colorado Springs, CO 80906, USA  
Tel: 1(719) 576-3300  
Fax: 1(719) 540-1759

Scottish Enterprise Technology Park  
Maxwell Building  
East Kilbride G75 0QR, Scotland  
Tel: (44) 1355-803-000  
Fax: (44) 1355-242-743

### RF/Automotive

Theresienstrasse 2  
Postfach 3535  
74025 Heilbronn, Germany  
Tel: (49) 71-31-67-0  
Fax: (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd.  
Colorado Springs, CO 80906, USA  
Tel: 1(719) 576-3300  
Fax: 1(719) 540-1759

### Biometrics/Imaging/Hi-Rel MPU/ High Speed Converters/RF Datacom

Avenue de Rochepleine  
BP 123  
38521 Saint-Egreve Cedex, France  
Tel: (33) 4-76-58-30-00  
Fax: (33) 4-76-58-34-80

## Literature Requests

[www.atmel.com/literature](http://www.atmel.com/literature)

**Disclaimer:** The information in this document is provided in connection with Atmel products. No license, express or implied, by estoppel or otherwise, to any intellectual property right is granted by this document or in connection with the sale of Atmel products. EXCEPT AS SET FORTH IN ATMEL'S TERMS AND CONDITIONS OF SALE LOCATED ON ATMEL'S WEB SITE, ATMEL ASSUMES NO LIABILITY WHATSOEVER AND DISCLAIMS ANY EXPRESS, IMPLIED OR STATUTORY WARRANTY RELATING TO ITS PRODUCTS INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTY OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT. IN NO EVENT SHALL ATMEL BE LIABLE FOR ANY DIRECT, INDIRECT, CONSEQUENTIAL, PUNITIVE, SPECIAL OR INCIDENTAL DAMAGES (INCLUDING, WITHOUT LIMITATION, DAMAGES FOR LOSS OF PROFITS, BUSINESS INTERRUPTION, OR LOSS OF INFORMATION) ARISING OUT OF THE USE OR INABILITY TO USE THIS DOCUMENT, EVEN IF ATMEL HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES. Atmel makes no representations or warranties with respect to the accuracy or completeness of the contents of this document and reserves the right to make changes to specifications and product descriptions at any time without notice. Atmel does not make any commitment to update the information contained herein. Unless specifically provided otherwise, Atmel products are not suitable for, and shall not be used in, automotive applications. Atmel's products are not intended, authorized, or warranted for use as components in applications intended to support or sustain life.

© Atmel Corporation 2005. All rights reserved. Atmel®, logo and combinations thereof, Everywhere You Are® and others, are registered trademarks or trademarks of Atmel Corporation or its subsidiaries. Other terms and product names may be trademarks of others.



Printed on recycled paper.